



晶体光学和电光器件

Crystal Optics and Electro-Optic Devices

(二)

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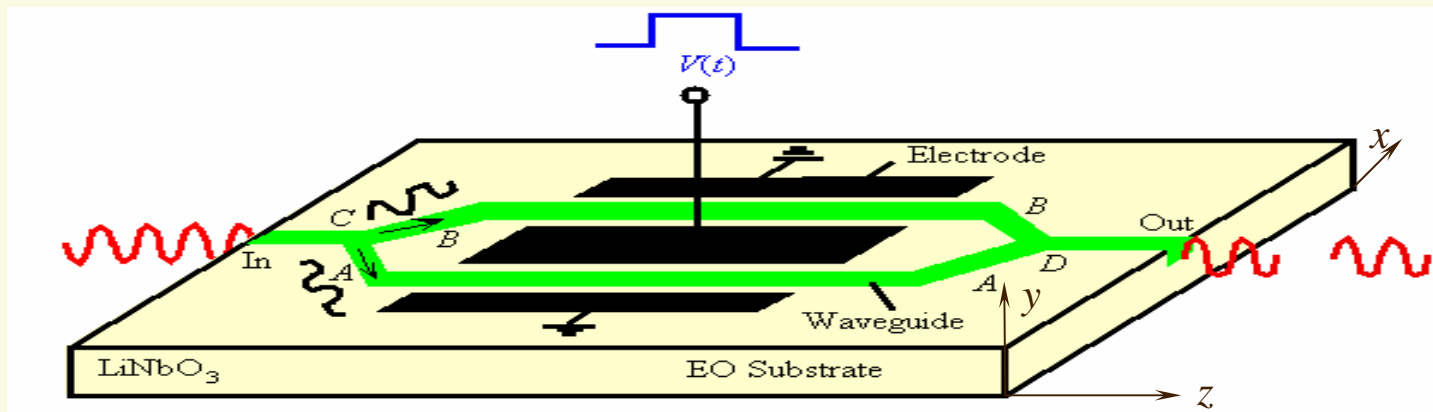
北京交通大学全光网与现代通信网教育部重点实验室

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北京交通大学

Integrated Mach-Zehnder Optical Modulators

➤ Device Structure



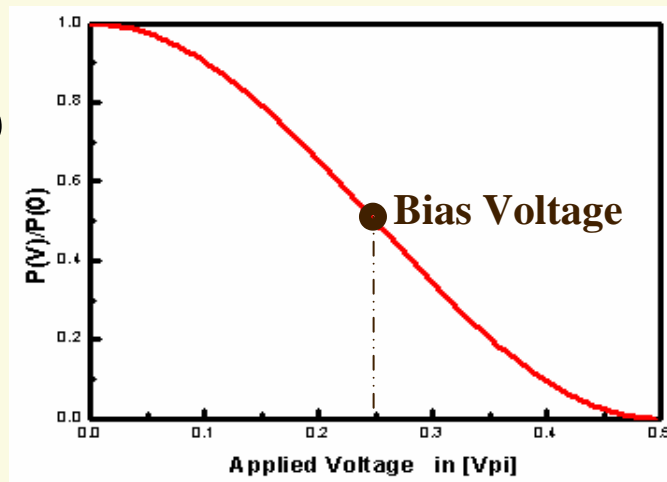
➤ Operating Principle

$$E_{out} \propto E_A \cos(\omega t + \Delta\phi) + E_B \cos(\omega t - \Delta\phi)$$

$$= 2E_A \cos(\Delta\phi) \cos(\omega t)$$

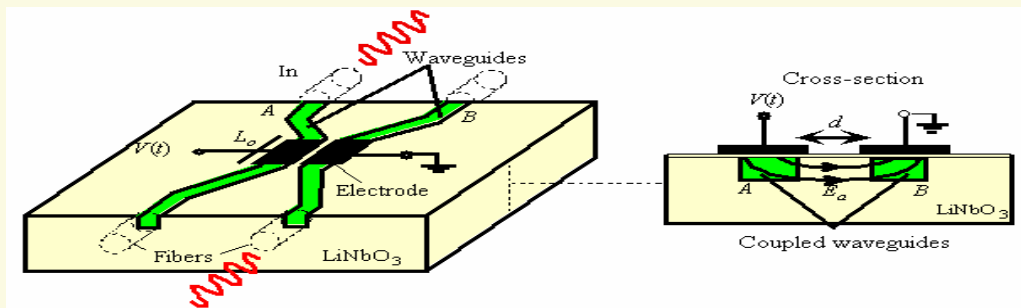
$$E_A \cong E_B \quad \text{and} \quad \Delta\phi = (\pi/V_\pi)V(t)$$

$$P_{out}[V(t)] = P_{out}(0) \cos^2[(\pi/V_\pi)V(t)]$$



Electro-Optic Directional Couplers and Modulators

➤ Device Structure



➤ Basic Principle

Consider only the coupling between TE fields:

$$\mathbf{E} \cong \mathbf{e}_x \left[A(z) E_A(x, y) e^{-j\beta_A z} + B(z) E_B(x, y) e^{-j\beta_B z} \right] e^{j\omega t}$$

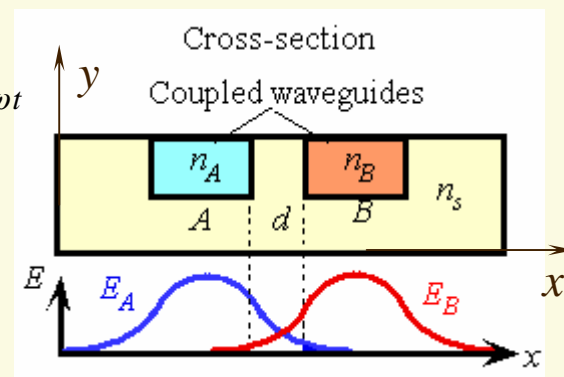
The general coupled wave Eqs. become:

$$dA/dz = -j\eta_A A - j\kappa_{AB} B e^{j(\beta_A - \beta_B)z}$$

$$dB/dz = -j\eta_B B - j\kappa_{BA} A e^{j(\beta_B - \beta_A)z}$$

If A and B are exactly the same, we have:

$\Delta \beta = \beta_A - \beta_B = 0$ for $V=0$. Phase matching condition is perfectly satisfied and the two fields are strongly coupled. The power in A will be transferred to B. For $V \neq 0$, $\Delta \beta \approx 2 \Delta n (2\pi / \lambda)$. $\Delta n = (1/2) n_o \gamma_{22} (V/d)$. The phase mismatch will destroy the coupling between the two fields and the power transfer decays.



Solutions to The Coupled Wave Equations

➤ Coupling Coefficiency

$$\kappa_{AB} = \frac{k_0}{2n_A} \int_{\text{inB}} (n_B^2 - n_s^2) E_A E_B^* dx dy \quad \kappa_{BA} = \frac{k_0}{2n_B} \int_{\text{inA}} (n_A^2 - n_s^2) E_B E_A^* dx dy$$

$$\delta_A = \frac{k_0}{2n_A} \int_{\text{inB}} (n_B^2 - n_s^2) |E_A|^2 dx dy \quad \delta_B = \frac{k_0}{2n_B} \int_{\text{inA}} (n_A^2 - n_s^2) |E_B|^2 dx dy$$

➤ Standard Form of The CWE

$$A(z) = R(z) e^{-j[\eta_A + \delta]z} \quad B(z) = S(z) e^{-j[\eta_B - \delta]z} \quad (\delta = \Delta\beta/2)$$

$$\longrightarrow R' - j\delta R = -j\kappa_{AB} S \quad S' - j\delta S = -j\kappa_{BA} R \quad (R(0) = 1, S(0) = 0)$$

➤ Solutions

$$R(z) = \cos(\Omega z) + j\delta [\sin(\Omega z)/\Omega] \quad S(z) = -j\kappa [\sin(\Omega z)/\Omega]$$

$$\kappa = |\kappa_{AB}| \approx |\kappa_{BA}| \quad \Omega = \sqrt{\kappa^2 + \delta^2}$$

$$\text{For } \Delta\beta = 0, \quad P_A(z) = \cos^2(\kappa z) \quad P_B(z) = \sin^2(\kappa z) \quad \longrightarrow \quad P_A(z) + P_B(z) = 1$$

$$\text{Generally:} \quad P_B(z) = P_{in} \left(\kappa^2 / \Omega^2 \right) \sin^2(\Omega z) \quad P_A(z) = P_{in} - P_B(z)$$

Summary

➤ Length of the Coupler for Fully Power Transfer

$$\kappa L = \pi/2$$

➔ $P_A(0) = 1$ $P_A(L) = 0$ and $P_B(0) = 0$ $P_B(L) = 1$ for $\Delta\beta = 0$ ($V = 0$)

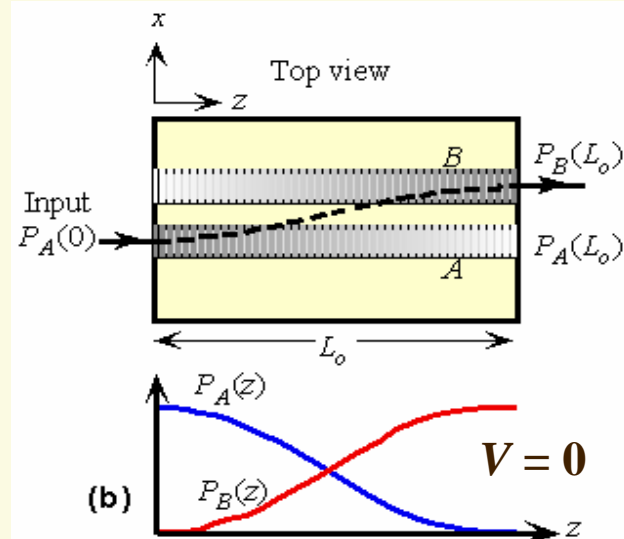
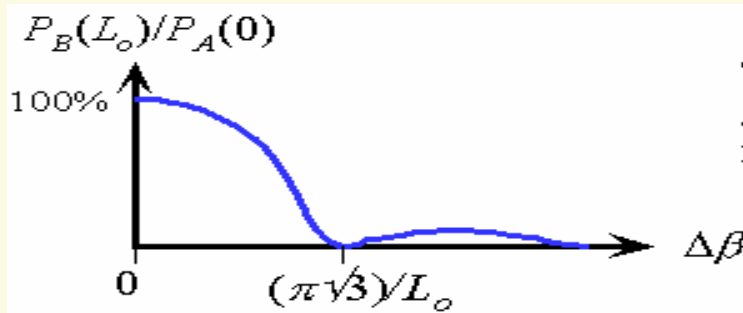
➤ Switching Voltage

$$\delta L = \Delta\beta L/2 = n_o^3 \gamma_{22} L (V/d) (\pi/\lambda) = \sqrt{3}\pi/2 \quad \text{➔} \quad \Omega L = \pi$$

➔ $P_A(0) = 1$ $P_A(L) = 1$ and $P_B(0) = 0$ $P_B(L) = 0$ for $V = \sqrt{3}\lambda d / 2 n_o^3 \gamma_{22} L$

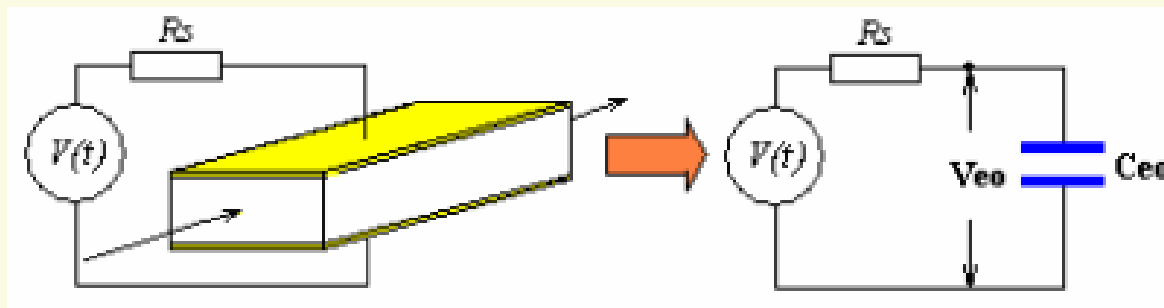
➤ Coupling Efficiency

$$\frac{P_B(L)}{P_{in}} = \frac{\kappa^2}{\kappa^2 + \delta^2} \sin^2(\sqrt{\kappa^2 + \delta^2} L)$$



High Frequency Modulation: A Simple Case

➤ Structure and Equivalent Circuit



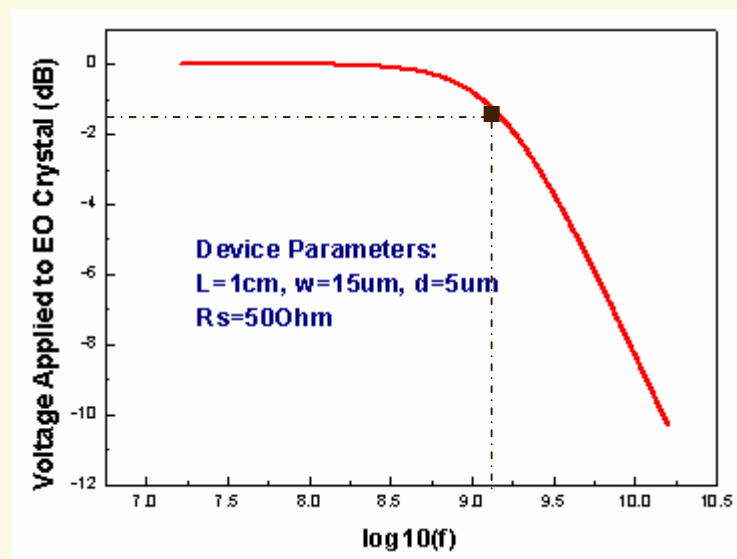
➤ Effective Applied Voltage

$$V_{eo}(\omega) \propto \frac{1}{\sqrt{1 + \omega^2 R_s^2 C_{eo}^2}}$$

R_s is the internal resistance of the signal source; $C_{eo} = \epsilon S/d$ is the capacitance of the modulator

$$f_{\max} = 1 / (2\pi \sqrt{R_s C_{eo}})$$

Reduce R_s and $C_{eo} = \epsilon S/d$ to achieve high frequency modulation



High Frequency Modulation: Improvement

➤ Equivalent Circuit

➤ The Effective Applied Voltage

$$V_{eo}(\omega) \propto \frac{1}{\sqrt{(\omega - \omega_0)^2 + (1/2R_p C_{eo})^2}}$$

The efficiency is maximum at $\omega = \omega_0$

$$\omega_0 = 1/\sqrt{LC_{eo}}$$

is the center frequency of the modulator

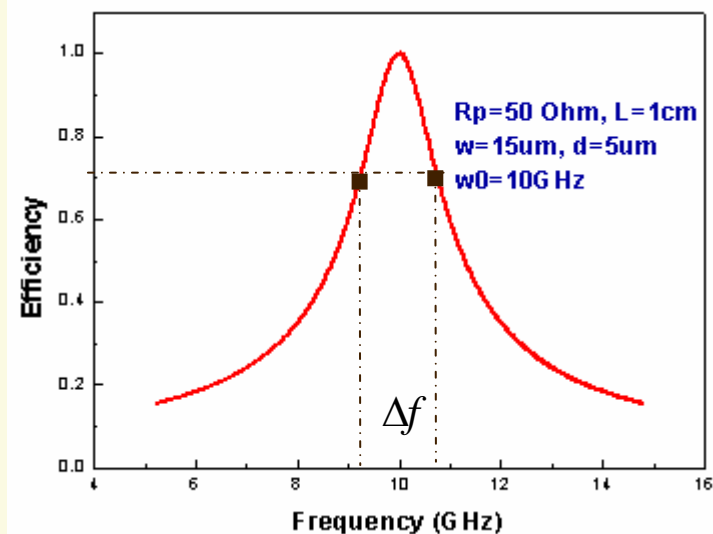
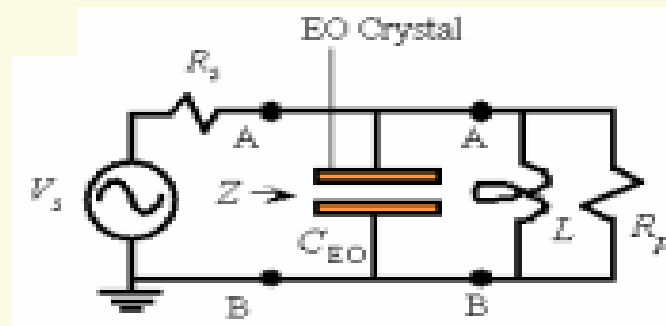
➤ Modulation Bandwidth

$$\Delta f = 1/(2\pi R_p C_{eo})$$

➤ Comments

Reduce R_s , L , and C_{eo} to achieve high frequency modulation

R_p should be properly selected



Transit-Time Limitations

➤ EO Retardation under High Speed Modulation

The EO phase retardation due to a low frequency field E can be written as:

$$\Delta\phi = \phi(E) - \phi(0) = aEL$$

For high speed modulation field $E(t)$, the retardation should be:

$$\Delta\phi = a \int_0^L E(z) dz = \frac{ac}{n} \int_{t-\tau}^t E(t') dt' \quad \tau = \frac{nL}{c} \text{ is the transit-time}$$

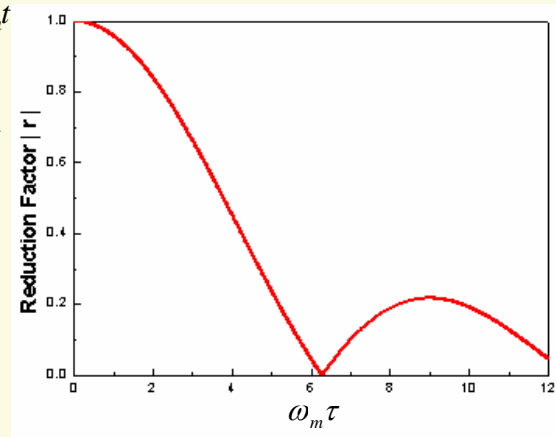
➤ Transit-Time Reduction Factor

Consider a sinusoid applied field: $E(t) = E_m e^{j\omega_m t}$

$$\Delta\phi = \frac{ac}{n} E_m \int_{t-\tau}^t e^{j\omega_m t'} dt' = aE_m L \left[\frac{1 - e^{-j\omega_m \tau}}{j\omega_m \tau} \right] e^{j\omega_m t}$$

$r = (1 - e^{-j\omega_m \tau}) / (j\omega_m \tau)$ is the reduction factor

For $\omega_m \tau \ll 1$, $r = 1$, and $\Delta\phi = aE(t)L$



➤ The Highest Modulation Frequency

$r = 0.9$ for $\omega_m \tau = \pi/2$, $(f_m)_{\max} = c/(4nL)$. For $n = 2.2$, $L = 1\text{cm}$, $(f_m)_{\max} = 3.4\text{GHz}$

Traveling-Wave Modulators

➤ The Traveling Modulation Field

$$E(z, t) = E_m e^{j(\omega_m t - k_m z)} = E_m e^{j\omega_m(t - z/c_m)}$$

➤ The Phase Retardation

Consider the optical field entering at time t .

At some later time t' , the field arrives at $z(t') = (c/n)(t' - t)$. At this point, the modulation field is:

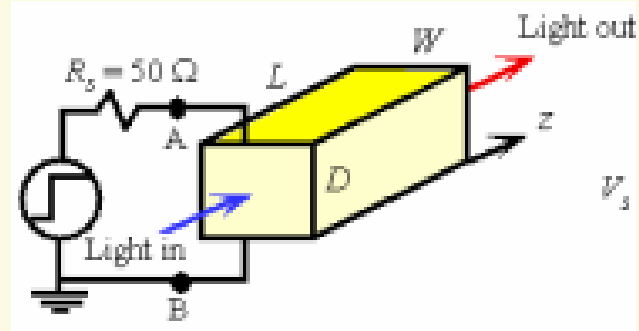
$$E(z, t) = E_m e^{j\omega_m[t' - c(t' - t)/(nc_m)]}$$

At time $t + \tau$ ($\tau = nL/c$), the optical field comes out from the crystal, and the total phase retardation obtained by the optical field is:

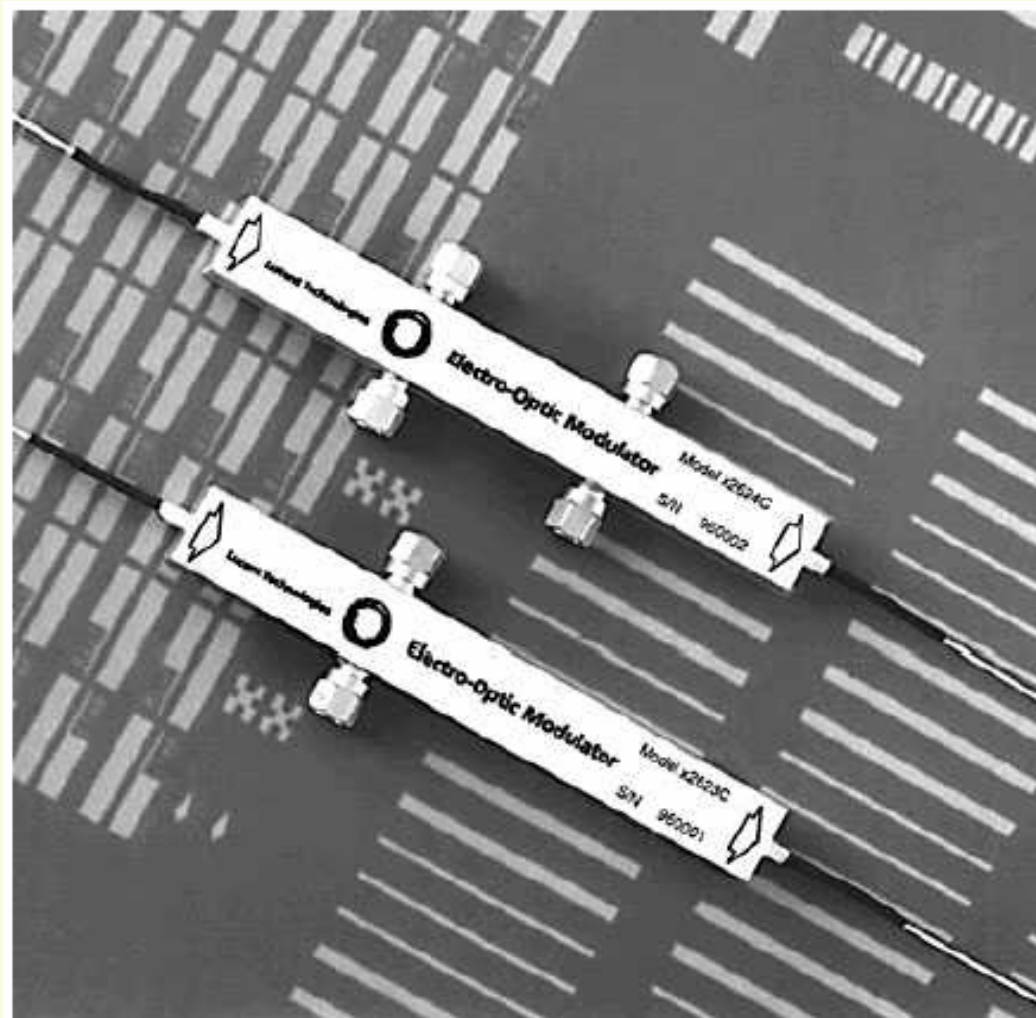
$$\Delta\phi = \frac{ac}{n} \int_t^{t+\tau} E(t', z(t')) dt' = aE_m L e^{j\omega_m t} \left[\frac{e^{j\omega_m \tau(1 - c/nc_m)} - 1}{j\omega_m \tau(1 - c/nc_m)} \right]$$

➤ The Reduction Factor and The Maximum Useful Frequency

$$r = \frac{e^{j\omega_m \tau(1 - c/nc_m)} - 1}{j\omega_m \tau(1 - c/nc_m)} \quad \longrightarrow \quad (f_m)_{\max} = \frac{c}{4nL(1 - c/nc_m)}$$



Ti Diffused LiNbO₃ MZ High Speed Modulators





Circular Birefringence Representation (CPR)

➤ The Basis Vectors in CPR

In CPR, the orthogonal and complete unit basis vector set are the CCW and CW rotating CP waves defined as $(1, 0)^T$ and $(0, 1)^T$. Arbitrary transverse field can be described as:

$$\mathbf{V} = V_+ \begin{Bmatrix} 1 \\ 0 \end{Bmatrix} + V_- \begin{Bmatrix} 0 \\ 1 \end{Bmatrix} = \begin{Bmatrix} V_+ \\ V_- \end{Bmatrix}$$

In rectangular representation, the same field is described as:

$$\mathbf{V} = V_x \begin{pmatrix} 1 \\ 0 \end{pmatrix} + V_y \begin{pmatrix} 0 \\ 1 \end{pmatrix} = \begin{Bmatrix} V_x \\ V_y \end{Bmatrix}$$

➤ The Transform Matrix

The two representation can be related by a transform matrix:

$$\begin{Bmatrix} V_+ \\ V_- \end{Bmatrix} = T \begin{Bmatrix} V_x \\ V_y \end{Bmatrix} \quad \text{and} \quad \begin{Bmatrix} V_x \\ V_y \end{Bmatrix} = T^{-1} \begin{Bmatrix} V_+ \\ V_- \end{Bmatrix}$$

From $\{0, 1\}^T = T(1, j)^T$, $\{1, 0\}^T = T(1, -j)^T$, we get:

$$T = \frac{1}{2} \begin{pmatrix} 1 & j \\ 1 & -j \end{pmatrix} \quad \text{and} \quad T^{-1} = \begin{pmatrix} 1 & 1 \\ -j & j \end{pmatrix}$$

Wave Propagation in Circularly Birefringent Medium

➤ The Jones Matrix of a Circularly Birefringent Medium

In a CB medium, the indices of CCW and CW CP waves are denoted by n_+ and n_- . The Jones matrix of CB medium of length L in CPR is:

$$J = \begin{pmatrix} e^{-j\theta_+} & 0 \\ 0 & e^{-j\theta_-} \end{pmatrix} = e^{-j(\theta_+ + \theta_-)/2} \begin{pmatrix} e^{j\theta} & 0 \\ 0 & e^{-j\theta} \end{pmatrix}$$

$$\begin{cases} \theta_+ = k_0 n_+ L, \theta_- = k_0 n_- L \\ \theta = (\theta_- - \theta_+)/2 \end{cases}$$

θ_+ and θ_- are the rotated angles of CCW and CW waves, respectively. Ignoring the common phase factor, the Jones matrix becomes:

$$J = \begin{pmatrix} e^{j\theta} & 0 \\ 0 & e^{-j\theta} \end{pmatrix}$$

The matrix in rectangular representation is obtained by transformation matrix T :

$$J' = T^{-1} J T = \begin{pmatrix} \cos \theta & -\sin \theta \\ \sin \theta & \cos \theta \end{pmatrix} = R(-\theta) \longrightarrow \begin{pmatrix} V_x(L) \\ V_y(L) \end{pmatrix} = J' \begin{pmatrix} V_x(0) \\ V_y(0) \end{pmatrix}$$

➤ Rotation of Polarization States

$$\begin{pmatrix} \cos \theta & -\sin \theta \\ \sin \theta & \cos \theta \end{pmatrix} \begin{pmatrix} 1 \\ 0 \end{pmatrix} = \begin{pmatrix} \cos \theta \\ \sin \theta \end{pmatrix}$$

A linearly-polarized input field is rotated by an angle θ after propagation in the CB medium.

Magneto-Optic (Faraday) Effects

➤ Faraday Rotation

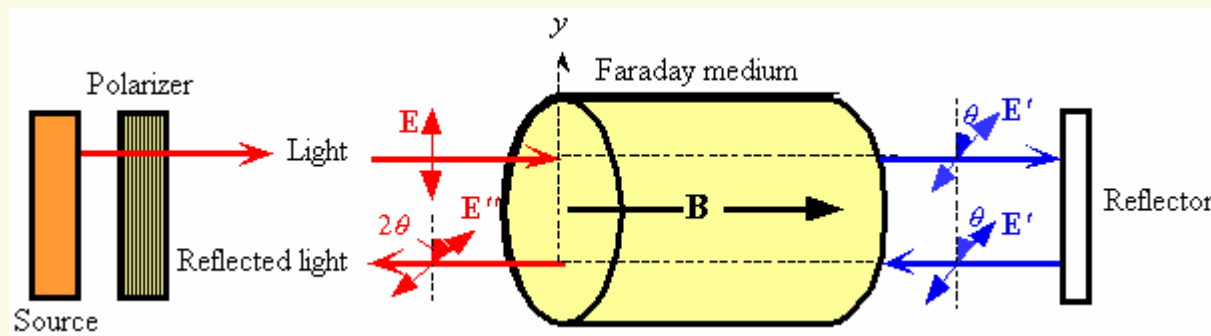
Some materials exhibit circular birefringence when a magnetic field is applied along the wave propagation direction. The birefringence $\Delta n = n_+ - n_-$ is proportional to the applied magnetic field, so the rotation angle can be written as (Faraday effect):

$$\theta = VBL \quad V \text{ is the Verdet constant of the material}$$

θ is the rotation angle about the direction of propagation.

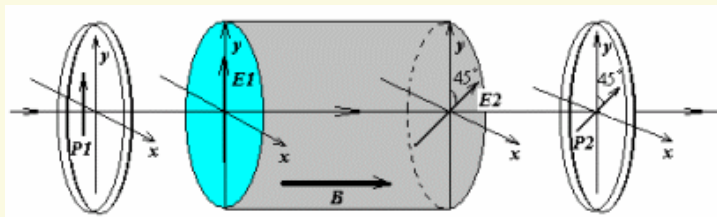
➤ Nonreciprocal Property of Faraday Rotation

For a wave traveling in the $-B$ direction, the rotation is $-\theta$ about the new direction of propagation. So the Faraday rotation is *nonreciprocal*. For a given material, the rotation direction depends only on the direction of B .

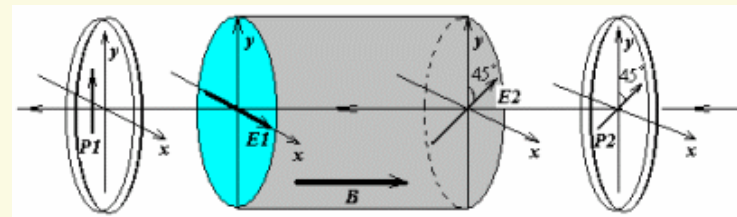


Optical Isolator

➤ Basic Principle



Forward Propagation Wave



Backward propagation Wave

➤ Improvement: Polarization Insensitivity

